HX7227-Q/HX7227-MS Dual 2:1 USB 2.0

Multiplexer/Demultiplexer with DC 30V Over-Voltage

Protection

DESCRIPTION

The HX7227-Q/HX7227-MS is a bidirectional, low-power dual-port high-speed USB 2.0 analog switch that features integrated protection for USB Type-C™ systems. This device can be configured as either a dual 2:1 or 1:2 switch and is optimized for use with the USB 2.0 DP/DM lines in a USB Type-C™ environment.

The HX7227-Q/HX7227-MS incorporates over-voltage protection on the C0+/- pins, capable of withstanding up to DC 30V, along with automatic shutoff circuitry designed to safeguard system components located behind the switch. The GPIO controls for SEL and EN are compatible with 1.8V logic levels.

Available in UQFN 1.4x18-10L and MSOP10 packages, both Pb-free and Halogen-free, the HX7227-Q/HX7227-MS is an ideal choice for mobile applications and environments where space is constrained.

FEATURES

- ★ Supply Range 2.5 V to 5.5 V
- ★ Differential 2:1 or 1:2 Switch/Multiplexer
- ★ Up to DC 30V Overvoltage Protection (OVP) on C0+/- Ports
- ★ IEC 64000-4-5 Surge Protection w/o External TVS onto C0+/- Ports: ±30V
- ★ System Side Clamp Voltage Pulse Less than 9V, Duration Less than 200nS
- Powered Off Protection When VDD = 0 V
- \bigstar Low R_{ON} of 10 Ω Typical
- ★ Insertion loss: -1dB@200MHz, -2dB@650MHz, -3dB@1GHz
- ★ C_{ON} of 4.8 pF
- ★ 1.8-V Compatible Logic Inputs Standard Temperature Range of -40°C to 85°C

APPLICATIONS

- ★ Anywhere a USB Type-C[™] or Micro-B Connector is Used
- USB 2.0 Signal Routing
- Digital Cameras and Camcorders
- Portable Instrumentation
- ★ Set-Top Box
- PADS the withstand USB devices
- 🖈 Mobile Phones, Tablets and Notebooks

Version 1.1 Date: Dec. 2023

ORDER INFORMATION

Model	Package	SPECIFIED TEMPERATURE RANGE	PACKING OPTION
HX7227-Q	UQFN 1.4x1.8-10L	-40°C to +85°C	Tape and Reel,3000
HX7227-MS	MSOP10	-40°C to +85°C	Tape and Reel,3000

PIN CONFIGURATION

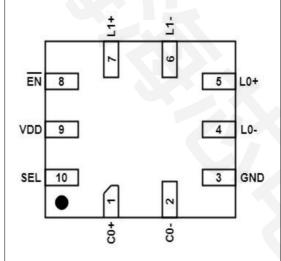


Figure 1. UQFN 1.4x1.8-10L

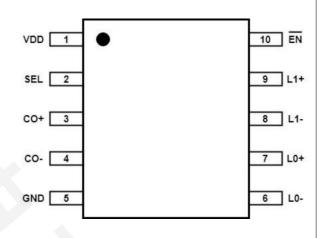


Figure 2. MSOP10

PIN DESCRIPTION

UQFN1.4x1.8-10L	MSOP10	Pin Name	Signal Type	Description
1	3	C0+	I/O	Signal I/O, Common Port
2	4	С0-	I/O	Signal I/O, Common Port
7	9	L1+	I/O	Signal I/O, Channle 1
6	8	L1-	I/O	Signal I/O, Channle 1
5	7	L0+	I/O	Signal I/O, Channle 0
4	6	L0-	I/O	Signal I/O, Channle 0
10	2	SEL I Operation Model Select (when SEL=0: C0→L0, when SEL=0: C0→L0, w		Operation Model Select (when SEL=0: C0→L0, when SEL=1: C0→L1)
8	10	_EN	I _EN= 1, Power Down is Enabled	
9	1	VDD	PWR	Positive Supply Voltage
3	3 5		GND	Power Ground

TRUTH TABLE

Function	SEL	_EN
C0+/- to L0+/-	L	L
C0+/- to L1+/-	Н	L
All Switches Hi-Z	X	Н

Typical Application

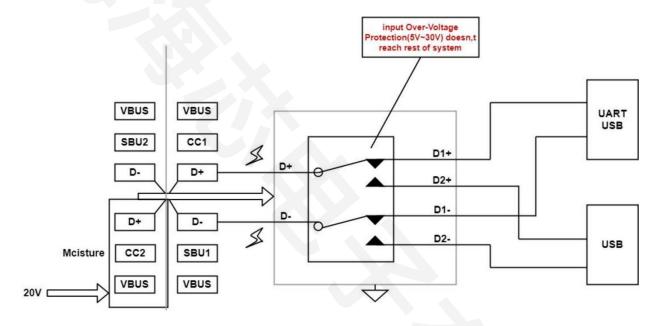


Figure 3. HX7227-Q/HX7227-MS Application circuit

In addition, considering the power consumption requirements of portable products, HX7227-Q/HX7227-MS is designed to minimize static power consumption. As shown in Figure 5 below, HX7227-Q/HX7227-MS integrates pull-down resistance up to 6 M Ω on both SEL and / OE pins. The weak pull-down resistance on the SEL pin saves power and ensures that channel 1 is opened in the default state, and the weak pull-down resistance on the OE pins ensures that the chip can work after power on.

FUNCTIONAL DIAGRAM

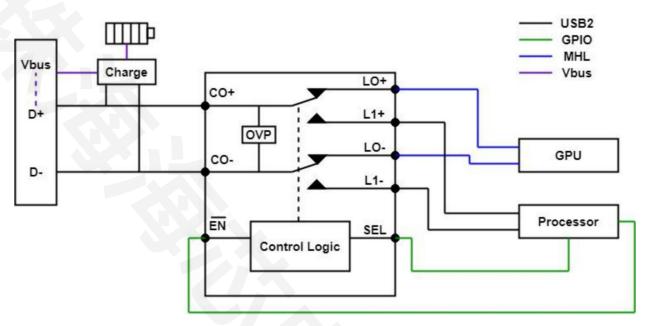


Figure 4. Function Diagram

The HX7227-Q/HX7227-MS is a high-speed, low-power dual-pole/dual-throw (DPDT) analog switch with 30V overvoltage protection and 2-way self-power supply. 5V to 5.5V. The HX7227-Q/HX7227-MS is used for high-speed USB 2.0 signal switching in handheld devices such as mobile phones, digital cameras, laptops, with hubs or controllers.

Overvoltage protection. As shown in Figure 5 below, the HX7227-Q/HX7227-MS has a special overvoltage protection circuit on the D + / D pin. When the USB device is powered on or off, the circuit can withstand the Vbus short circuit to D + or up to 30V, ensuring that the device is not damaged, and isolate the high voltage from the downstream circuit, protecting the downstream circuit. The OVP circuit integrated into the switch chip also greatly simplifies the design, reduces the size of the scheme, and solves the pain points of designers in practical applications. Please refer to the figure below.

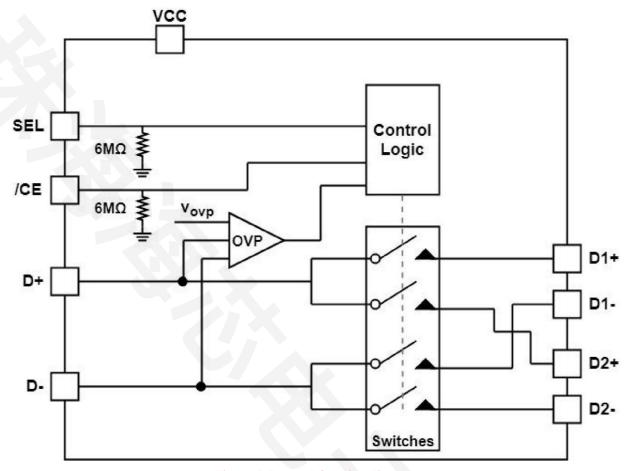
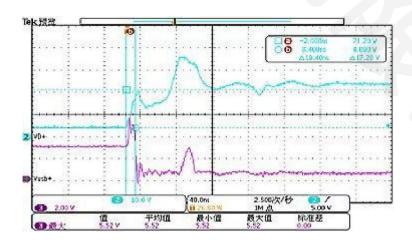


Figure 5. Internal function diagram

As shown in Figure 6 below, when the voltage on the data line is too high, the OVP protection circuit inside HX7227-Q/HX7227-MS starts to work, and the maximum voltage is as high as 5.5V, OVP responds, and the response speed is very fast, the average response time is 10.4nS, which can quickly disconnect, and protect the internal circuit from being damaged by high voltage loading.

Vcc=3.3V Full bandwidth VD=4.0-21V USB Load=50ohm Cusb + = 5 pF



The maximum of 5.5V OVP response time was 10.4nS

Figure 6. HX7227-Q/HX7227-MS High-pressure test

ELECTRICAL CHARACTERISTICS

(T_A=25°C, VDD=3.3V, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
POWER SUPPLY						
Supply Voltage Range	VDD		2.5	3.3	5.5	V
		_EN = 1 disconnection		0.6	2	uA
Supply Current	Icc	_EN =0 connection		33		uA
SEL/_EN DIGITAL INPUT C	CONTOL					1
control input logic high	VIH		1.6		5.5	V
control input logic low	VIL		-0.1		0.5	V
Internal pull-down resistor	Rpd			2		ΜΩ
SWITCH ON RESISTANCE	AND OFF	LEAKAGE				
On-Resistance	Ron	V _{IS} = 0V~0.4V I _{OUT} =8mA		10	11	Ω
R _{ON} Flatness ⁽¹⁾	RFLAT	V _{IS} = 0V~0.4V I _{OUT} =8mA		0.3	0.5	Ω
R _{ON} Matching Between Channels ⁽²⁾	ΔR on	V _{IS} = 0V~0.4V IOUT=8mA		0.1	0.2	Ω
OFF Leakage Current	I _{LEAK}	$V_{C0+/-} = 10V V_{L1+/-} = V_{D2+/-} = 0V$		31	50	uA
SWITCH DYNAMICS						
On Capacitance	Con	$V_{C0+/-} = 0.2V, f = 1MHz$		4		pF
Off Capacitance				3		pF
Off Isolation	f Isolation Off $f = 250 \text{MHz}, R_T = 500$, $C_L = 0 \text{pF}$			-38		dB
Crosstalk ⁽³⁾				1.1		1D
(Channel-to-Channel) X_{TALK} $t = 250M$		$f = 250 MHz, R_T = 50Q, C_L = 0pF$		-41		dB
-3dB Bandwidth	BW	R _T =50 Q , C _L =0pF Signal Power	0.9	1		CHa
		0dBm		1		GHz
Break-Before-Make	BBM	$V_{L1+/-} = V_{D2+/-} = 0.4V, R_L = 50Q$		1.5		uS
T T:		$V_{C0+/-} = 0.4V, R_L=500$		20		,,c
Turn-on Time	ton	_EN switches from High to Low		20		uS
Turn-off Time		$V_{C0+/-} = 0.4V, R_L=50Q$		1.2		uS
Turn-ori Time	toff	_EN switches from Low to High		1.2		us
Propagation Delay	t PD	$V_{C0+/-} = 0.4V, R_L = 50Q$		200		pS
OVER VOLTAGE PROTECT	ΓΙΟΝ					
OVP Lockout Threshold	Vovp	V _{C0+/-} Rising Edge	4.6	4.9	5.2	V
OVP Hysteresis	V _{HYS}	V _{C0+/-} Falling Edge		200		mV
Clamp Voltage on L1+/- and	VCLAMP	10V shorts to C0+/-		6.5	o	17
D2+/-		with $R_L = 1KQ$ @ L1+/- and D2+/-		6.5	8	V
OVP Response Time		10V shorts to C0+/-		200	300	nS
O vi Response Time	tfp	with $R_L = 1KQ$ @ L1+/- and D2+/-			300	113
OVP Recovery Time	tfpr	V _{C0+/-} jumps from 6V to 1V step	30	45	60	uS

Note:

- (1) Flatness is defined as the difference between maximum and minimum value of ON-resistance at the specified analog signal voltage points.
- (2) R_{ON} matching between channels is calculated by subtracting the channel with the lowest max Ron value from the channel with the highest max Ron value.
- (3) Crosstalk is inversely proportional to source impedance

TYPICAL PERFORMANCE CURVES

T_A=25°C, VDD=3.0V, CAP=0. 1uF, unless otherwise noted



Fig 7. Switch Bandwidth or Insertion Loss

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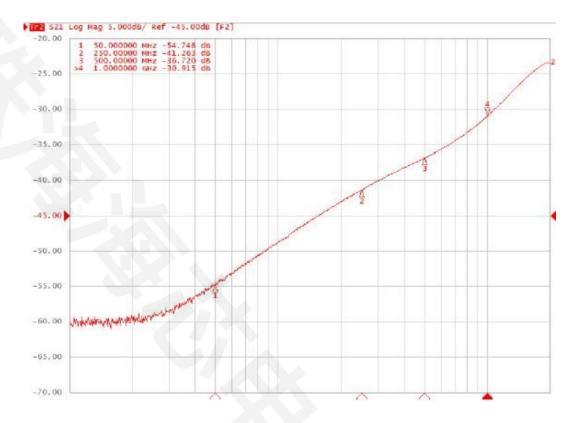


Fig 8. Switch Channel to Channel Cross-Talk

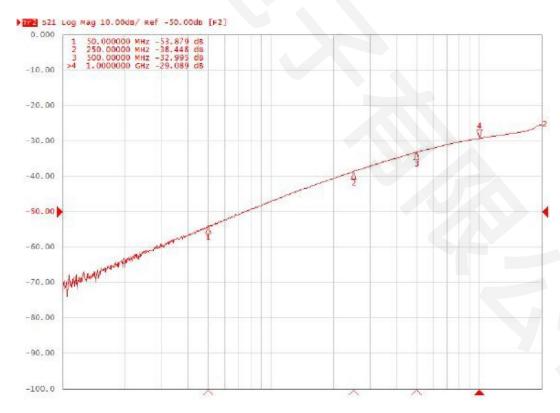
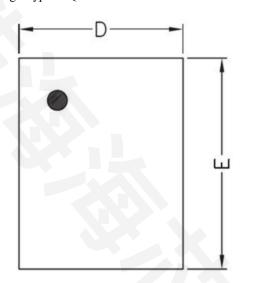
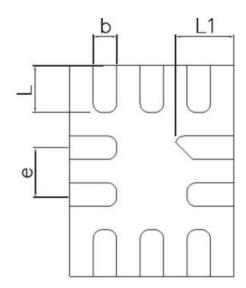


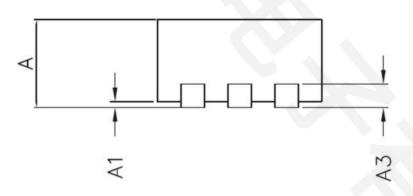
Fig 9. Switch Off Isolation

PACKAGE OUTLIHNE DIMENSIONS(All dimensions in mm.)

(1) Package Type: UQFN 1.4x1.8 -10L





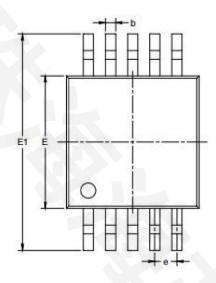


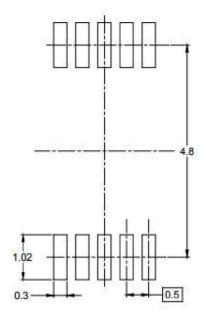
Const. I	Dimension in Millimeters		
Symbol	Min.	Max.	
A	0.450	0.550	
A1	0.000	0.050	
A3	0.152 Ref.		
D	1.350	1.450	
Е	1.750	1.850	
b	0.150	0.250	
e	0.400 Тур.		
L	0.350	0.450	
L1	0.450	0.550	

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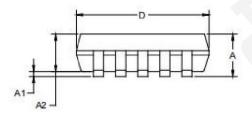
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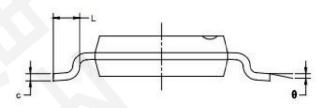
(2) Package Type: MSOP10





RECOMMENDED LAND PATTERN (Unit: mm)





	Dimensions		Dimensions		
Symbol	In Millimeters		In Inches		
	MIN	MAX	MIN	MAX	
A	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.180	0.280	0.007	0.011	
с	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
Е	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
e	0.500BSC		0.020BSC		
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	

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